

18V, 3A, 340KHz Synchronous Step-Down DC/DC Converter

Description

The FR9884 is a synchronous step-down DC/DC converter that provides wide 4.5V to 18V input voltage range and 3A continuous load current capability.

Fault protection includes cycle-by-cycle current limit, input UVLO, output over voltage protection and thermal shutdown. Besides, adjustable soft-start function prevents inrush current at turn-on. This device uses current mode control scheme that provides fast transient response. In shutdown mode, the supply current is about 10 μ A.

The FR9884 is available in an 8-pin SOIC package, which provides a very compact system solution and good thermal conductance.

Features

- Wide Input Voltage from 4.5V to 18V
- 3A Output Current
- Adjustable Output Voltage from 0.925V to 14V
- Low Rds(on) Integrated Power MOSFET
- High Efficiency up to 93%
- Fixed 340KHz Switching Frequency
- Current Mode Operation
- Adjustable Soft-Start
- Cycle-by-Cycle Current Limit
- Input Under Voltage Lockout
- Over-Temperature Protection With Auto Recovery
- 10 μ A Shutdown Current
- Thermal Enhanced SOP-8 (Exposed Pad) Package
- RoHS Compliant

Applications

- Set-Top-Box
- DVD, LCD Display
- OLPC, Netbook
- Distributed Power System
- Datacom, XDSL

Pin Assignments

SP Package (SOP-8 Exposed Pad)

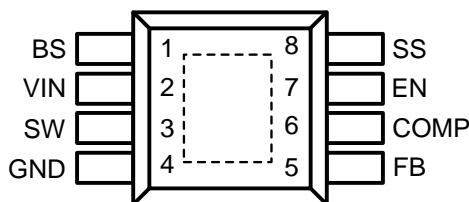
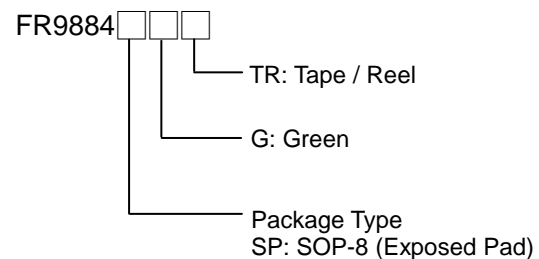


Figure 1. Pin Assignment of FR9884

Ordering Information



Typical Application Circuit

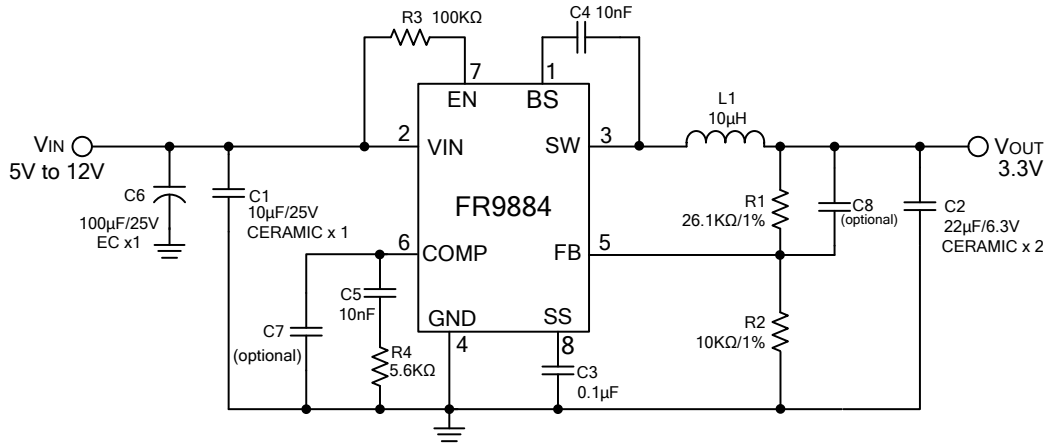


Figure 2. Output 3.3V Application Circuit

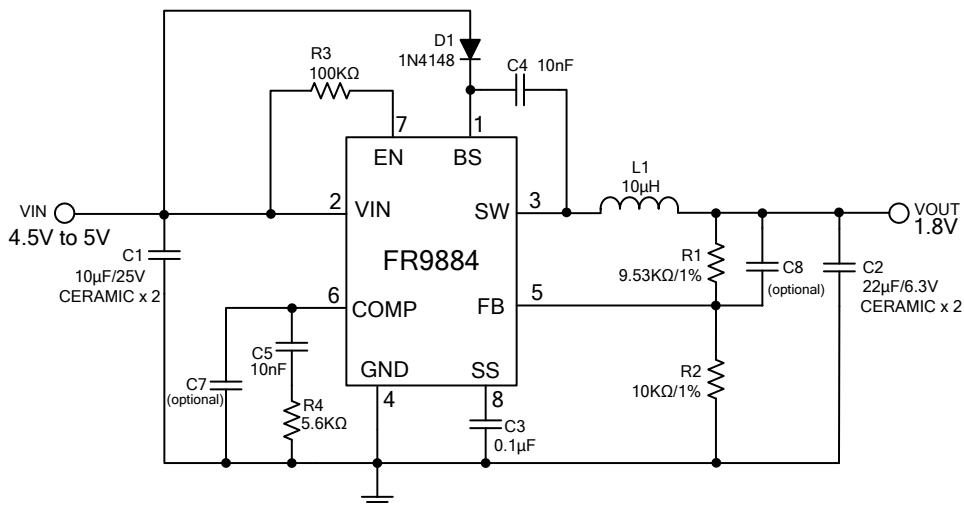


Figure 3. Low Input Voltage Application Circuit

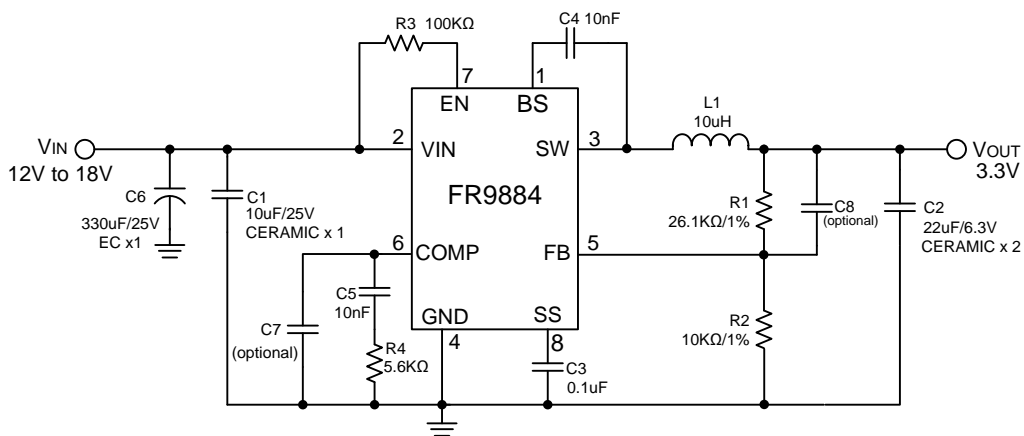


Figure 4. High Input Voltage Application Circuit

Functional Pin Description

Pin Name	Pin Function
BS	High Side Gate Drive Boost Input. A 10nF or greater capacitor must be connected from this pin to SW. It can boost the gate drive to fully turn on the internal high side NMOS.
VIN	Power Supply Input Pin. Drive 4.5V to 18V voltage to this pin to power on this chip.
SW	Power Switching Output. It is the output pin of internal high side NMOS which is the switch to supply power.
GND	Ground Pin. Connect this pin to exposed pad.
FB	Voltage Feedback Input Pin. Connect FB and VOUT with a resistive voltage divider. This IC senses feedback voltage via FB and regulates it at 0.925V.
COMP	Compensation Pin. This pin is used to compensate the regulation control loop. Connect a series RC network from COMP pin to GND.
EN	Enable Input Pin. This pin provides a digital control to turn the converter on or off. Connect to VIN with a 100KΩ resistor for self-startup.
SS	Soft-Start Input Pin. This pin controls the soft-start period. Connect a capacitor from SS to GND to set the soft start period.

Block Diagram

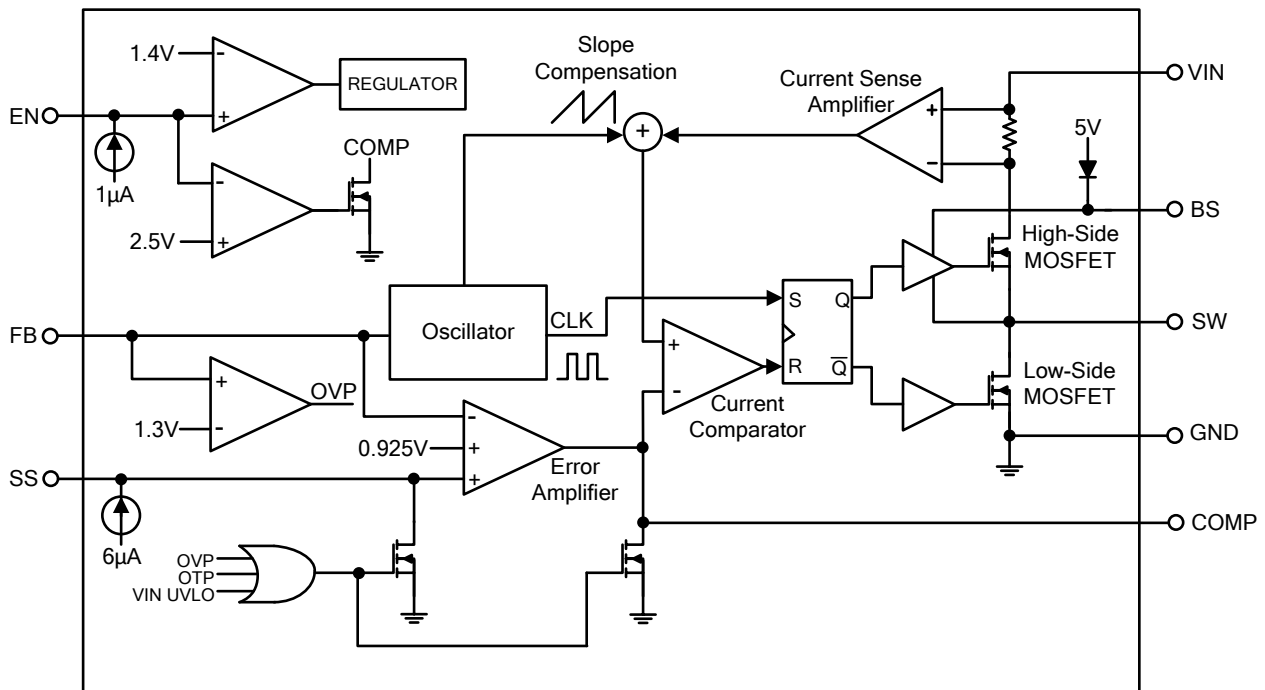


Figure 5. Block Diagram of FR9884

Absolute Maximum Ratings

- Input Supply Voltage V_{IN} ----- -0.3V to +21V
- SW Voltage V_{SW} ----- -1V to $V_{IN} + 0.3V$
- Boost Trap Voltage V_{BS} ----- $V_{sw} - 0.3V$ to $V_{sw} + 6V$
- All Other Pins Voltage ----- -0.3V to +6V
- Maximum Junction Temperature (T_J) ----- +150°C
- Storage Temperature (T_S) ----- -65°C to +150°C
- Lead Temperature (Soldering, 10sec.) ----- +260°C
- Power Dissipation @ $T_A=25^\circ C$, (P_D)
 - SOP-8 (Exposed Pad) ----- 1.25W
- Package Thermal Resistance, (θ_{JA}):
 - SOP-8 (Exposed Pad) ----- 50°C/W
- Package Thermal Resistance, (θ_{JC}):
 - SOP-8 (Exposed Pad) ----- 15°C/W

Note 1 : Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

Recommended Operating Conditions

- Input Supply Voltage (V_{IN}) ----- +4.5V to +18V
- Output Voltage (V_{OUT}) ----- +0.925V to +14V
- Operation Temperature Range ----- -40°C to +85°C

Electrical Characteristics

($V_{IN}=12V$, $T_A=25^{\circ}C$, unless otherwise specified.)

Parameter	Conditions	Min	Typ	Max	Unit
V_{IN} Input Supply Voltage (Note 2)		4.5		18	V
V_{IN} Supply Current	$V_{EN} = 1.8V$		1.1		mA
V_{IN} Shutdown Supply Current	$V_{EN} = 0V$		10	15	μA
Feedback Voltage	$4.5V \leq V_{IN} \leq 18V$	0.9	0.925	0.95	V
Feedback OVP Threshold Voltage			1.3		V
High-Side MOSFET RDS(ON) (Note 3)			120		m Ω
Low-Side MOSFET RDS(ON) (Note 3)			80		m Ω
High-Side MOSFET Leakage Current	$V_{EN} = 0V$, $V_{SW} = 0V$			10	μA
High-Side MOSFET Current Limit (Note 3)	Minimum Duty	3.8	5		A
Low-Side MOSFET Current Limit (Note 3)			3		A
Current sense to COMP Transconductance (Note 3)			3.5		A/V
Error Amplifier Transconductance (Note 3)	$\Delta I_{COMP} = \pm 10\mu A$		1600		$\mu A/V$
Error Amplifier Voltage Gain (Note 3)			400		V/V
Oscillation frequency		280	340	400	KHz
Short Circuit Oscillation Frequency	$V_{FB} = 0V$		110		KHz
Maximum Duty Cycle	$V_{FB} = 0.8V$		90		%
Minimum On Time (Note 3)			200		ns
Input UVLO Threshold	V_{IN} Rising		4.4		V
Under Voltage Lockout Threshold Hysteresis			400		mV
Soft-Start Current			6		μA
Soft-Start Period	$C_{SS} = 0.1\mu F$		15		ms
EN Lockout Threshold Voltage		2.3	2.5	2.7	V
EN Shutdown Threshold Voltage		1.1	1.4		V
Thermal Shutdown Threshold (Note 3)			160		$^{\circ}C$

Note 2 : When $V_{IN} = 4.5V$, $V_{OUT} = 3.3V$, maximum load current is about 2A.

Note 3 : Not production tested.

Typical Performance Curves

$V_{IN} = 12V$, $V_{OUT} = 3.3V$, $C1 = 10\mu F \times 1$, $C6 = 100\mu F \times 1$, $C2 = 22\mu F \times 2$, $L1 = 10\mu H$, $T_A = +25^\circ C$, unless otherwise noted.

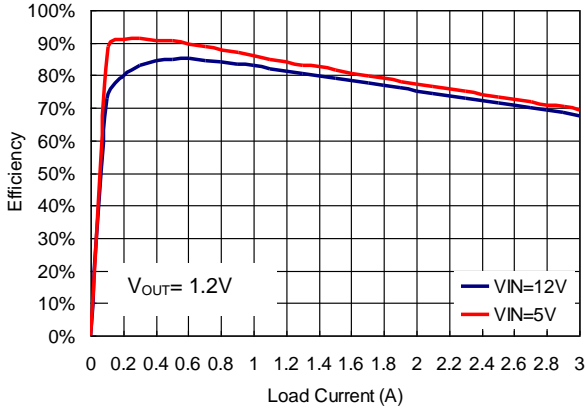


Figure 6. Efficiency vs. Loading

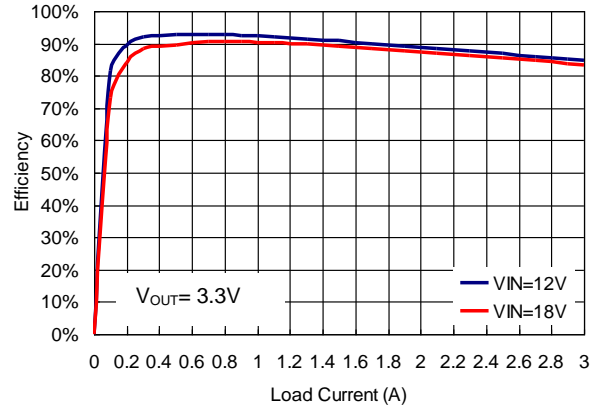


Figure 7. Efficiency vs. Loading

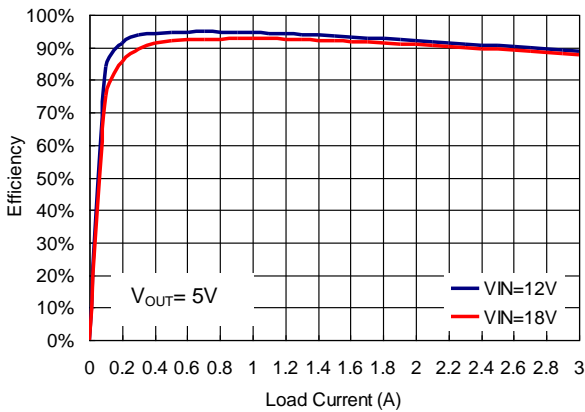


Figure 8. Efficiency vs. Loading

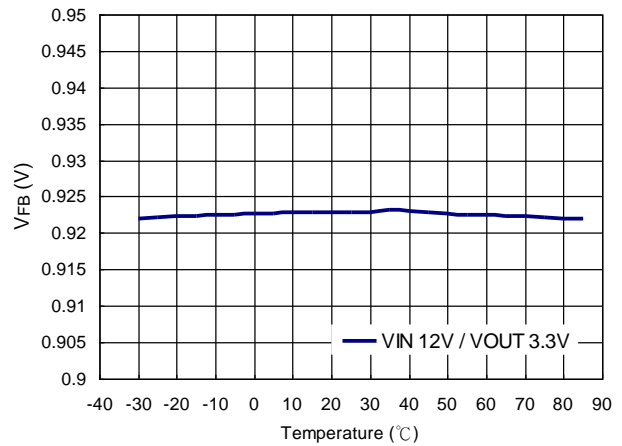


Figure 9. Feedback Voltage vs. Temperature

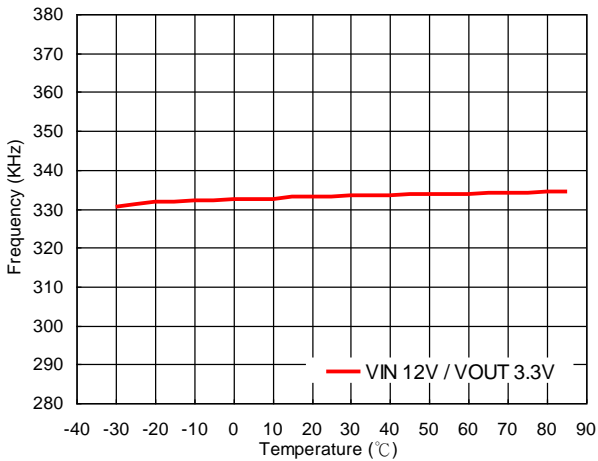


Figure 10. Frequency vs. Temperature

Typical Performance Curves (Continued)

$V_{IN} = 12V$, $V_{OUT} = 3.3V$, $C1 = 10\mu F \times 1$, $C6 = 100\mu F \times 1$, $C2 = 22\mu F \times 2$, $L1 = 10\mu H$, $T_A = +25^\circ C$, unless otherwise noted.

$I_{OUT} = 0A$

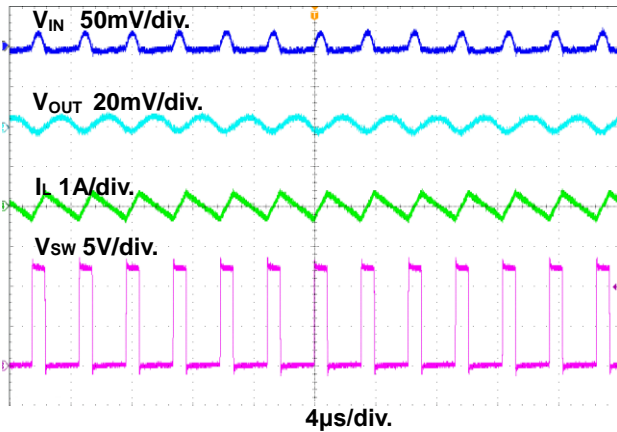


Figure 11. DC Ripple Waveform

$I_{OUT} = 3A$

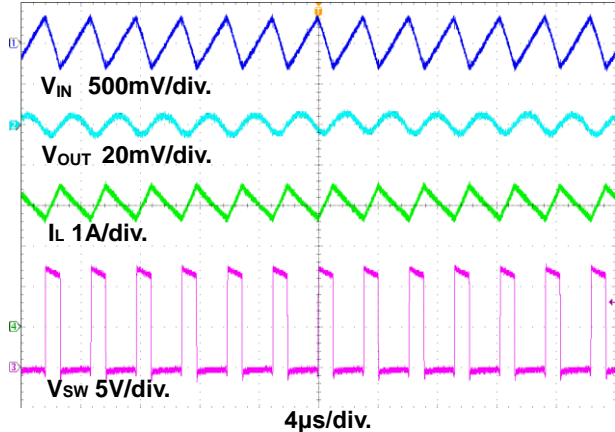


Figure 12. DC Ripple Waveform

$I_{OUT} = 0.1A$

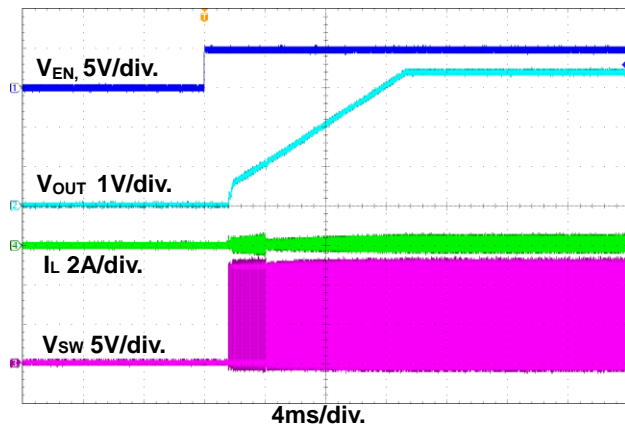


Figure 13. Startup Through Enable Waveform

$I_{OUT} = 3A$

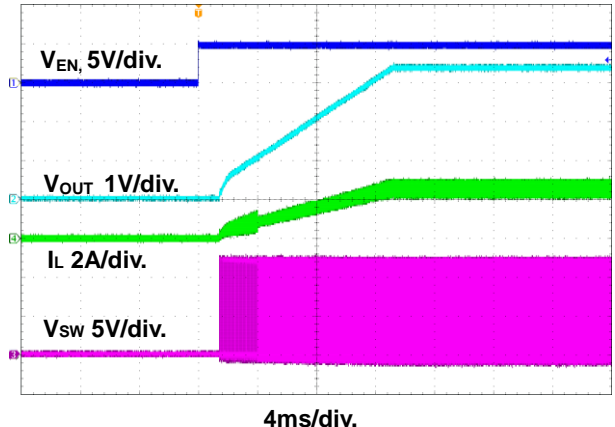


Figure 14. Startup Through Enable Waveform

$I_{OUT} = 0.1A$

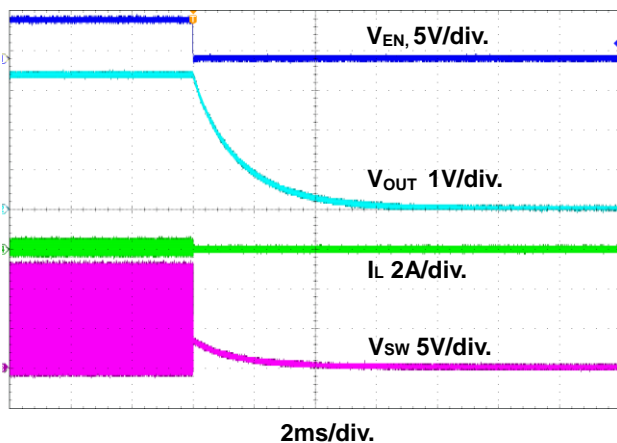


Figure 15. Shutdown Through Enable Waveform

$I_{OUT} = 3A$

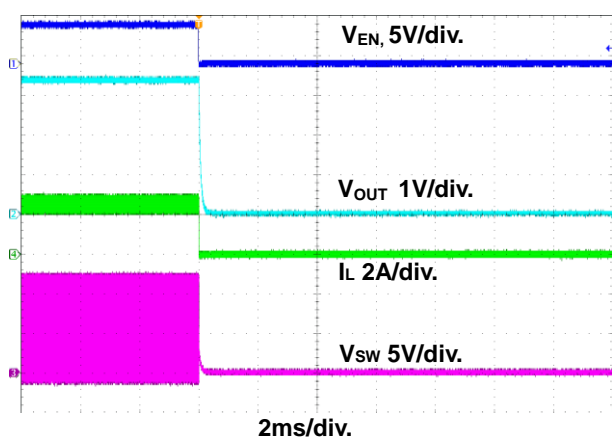


Figure 16. Shutdown Through Enable Waveform

Typical Performance Curves (Continued)

$V_{IN} = 12V$, $V_{OUT} = 3.3V$, $C1 = 10\mu F \times 1$, $C6 = 100\mu F \times 1$, $C2 = 22\mu F \times 2$, $L1 = 10\mu H$, $T_A = +25^\circ C$, unless otherwise noted.

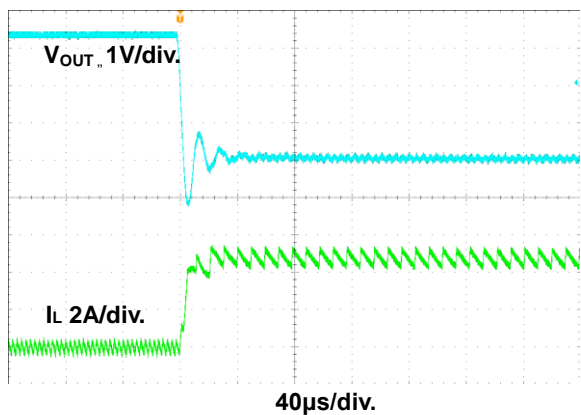


Figure 17. Short Circuit Test Waveform

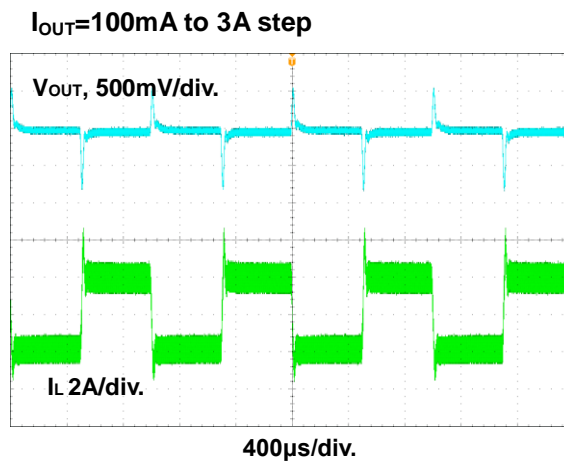


Figure 18. Load Transient Waveform

Function Description

The FR9884 is a constant frequency current mode step-down synchronous DC/DC converter. It regulates input voltage from 4.5V to 18V, down to an output voltage as low as 0.925V, and provides 3A of continuous load current.

Control Loop

During normal operation, the output voltage is sensed at FB pin by a resistive voltage divider and amplified through the error amplifier. The voltage of error amplifier output pin -- COMP is compared to the switch current to controls the RS latch. At each cycle, the high side NMOS will be turned on when the oscillator sets the RS latch and turned off when current comparator resets the RS latch. When the load current increases, the FB pin voltage will drop below 0.925V, and it will cause the COMP voltage increasing until average inductor current arrives at new load current.

Enable

The FR9884 EN pin provides digital control to turn on/off the regulator. When the voltage of EN exceeds the threshold voltage, the regulator will start the soft start function. If the EN pin voltage is below the threshold voltage, only the bandgap voltage will be alive. If the EN pin voltage is below the shutdown threshold voltage, the regulator will be disabled and turn into the shutdown mode.

Maximum Load Current

The maximum load current decreases at lower input voltage because of large IR drop on the high side switch and low side switch. The slope compensation signal reduces the peak inductor current as a function of the duty cycle to prevent sub-harmonic oscillations when duty cycles are greater than 50%.

Output Over Voltage Protection

When the FB pin voltage exceeds 1.3V, the output over voltage protection function will discharge the COMP pin and the SS pin to GND to turn the high side MOSFET off.

Input Under Voltage Lockout

When the FR9884 is power on, the internal circuits will be held inactive until V_{IN} exceeds the input UVLO threshold voltage. And the regulator will be disabled when V_{IN} is below the input UVLO threshold voltage. The hysteresis of the UVLO comparator is 400mV.

Short Circuit Protection

The FR9884 provides short circuit protection function to prevent the device damaged from short condition. When the output is short to ground, the oscillator frequency will be reduced to prevent the inductor current increasing beyond the current limit. In the meantime, the current limit will also be reduced to lower the short current. Once the short condition is removed, the frequency and current limit will return to normal.

Over Temperature Protection

The FR9884 incorporates an over temperature protection circuit to protect itself from overheating. When the junction temperature exceeds the thermal shutdown threshold temperature, the regulator will be shut down and re-enabled when the IC junction temperature drops 30°C (typ).

Compensation

The stability of the feedback circuit is controlled by COMP pin. The compensation value of the application circuit is optimized for particular requirements. If different conversions are required, some of the components may need to be changed to ensure stability.

Application Information

Output Voltage Setting

The output voltage V_{OUT} is set by using a resistive divider from the output to FB. The FB pin regulated voltage is 0.925V. Thus the output voltage is:

$$V_{OUT} = 0.925 \times \left(1 + \frac{R1}{R2}\right) V$$

R2 recommended value is 10kΩ, so R1 is determined by:

$$R1 = 10.81 \times (V_{OUT} - 0.925) k\Omega$$

Table 1 lists recommended values of R1 and R2 for most used output voltage.

Table 1 Recommended Resistance Values

V_{OUT}	R1	R2
5V	44.2 kΩ	10 kΩ
3.3V	26.1 kΩ	10 kΩ
2.5V	16.9 kΩ	10 kΩ
1.8V	9.53 kΩ	10 kΩ
1.2V	3 kΩ	10 kΩ

Place resistors R1 and R2 close to FB pin to prevent stray pickup.

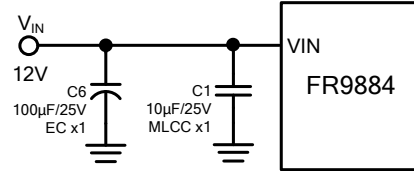
Input Capacitor Selection

The use of the input capacitor is controlling the input voltage ripple and the MOSFETS switching spike voltage. Because the input current to the step-down converter is discontinuous, the input capacitor is required to supply the current to the converter to keep the DC input voltage. The capacitor voltage rating should be 1.25 to 1.5 times greater than the maximum input voltage. The input capacitor ripple current RMS value is calculated as:

$$I_{IN(RMS)} = I_{OUT} \times \sqrt{D \times (1-D)}$$

Where D is the duty cycle of the power MOSFET.

A low ESR capacitor is required to keep the noise minimum. Ceramic capacitors are better, but tantalum or low ESR electrolytic capacitors may also suffice. When using tantalum or electrolytic capacitors, a 10μF ceramic capacitor should be placed as close to the IC as possible.



It is recommended that the input EC capacitor could be added for applications if the FR9884 suffers high spike input voltage (ex. hot plug test). It can eliminate the spike voltage induced the IC damaged from high input voltage stress (see Note 1).

Table 2 lists recommended values of C1 and C6 for most used input voltage.

Table 2 Recommended Capacitor Values

V_{IN}	C1	C6
5V	10μF X2	---
12V	10μF X1	100μF X1
15V	10μF X1	330μF X1
18V	10μF X1	330μF X1

Output Capacitor Selection

The output capacitor is used to keep the DC output voltage and supply the load transient current. Low ESR capacitors are preferred. Ceramic, tantalum or low ESR electrolytic capacitors can be used depending on the output ripple requirement. Add a 100μF or 470μF Low ESR electrolytic capacitor when operating in high input voltage range. It can improve the device's stability. The output ripple voltage ΔV_{OUT} is described as:

$$\Delta I = \frac{V_{OUT}}{F_{OSC} \times L} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

$$\Delta V_{OUT} = \Delta I \times \left(R_{ESR} + \frac{1}{8 \times F_{OSC} \times C_{OUT}} \right)$$

Where ΔI is the peak-to-peak inductor ripple current, F_{OSC} is the switching frequency, L is the inductance value, V_{IN} is the input voltage, V_{OUT} is the output voltage, R_{ESR} is the equivalent series resistance value of the output capacitor, and the C_{OUT} is the output capacitor. When using the ceramic capacitors, the RESR can be ignored and the output ripple voltage ΔV_{OUT} is shown as:

$$\Delta V_{OUT} = \frac{\Delta I}{8 \times F_{OSC} \times C_{OUT}}$$

Application Information (Continued)

Output Inductor Selection

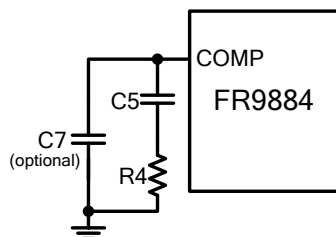
The output inductor is used for storing energy and filtering output ripple current. But the trade-off condition often happens between maximum energy storage and the physical size of the inductor. The first consideration for selecting the output inductor is to make sure that the inductance is large enough to keep the converter in the continuous current mode. That will lower ripple current and result in lower output ripple voltage. A good rule for determining the inductance is setting the peak-to-peak inductor ripple current ΔI almost equal to 30% of the maximum load current. Then the minimum inductance can be calculated with the following equation:

$$\Delta I = 0.3 \times I_{OUT(MAX)}$$

$$L \geq (V_{IN} - V_{OUT}) \times \left(\frac{V_{OUT}}{F_{OSC} \times \Delta I \times V_{IN}} \right)$$

Where V_{IN} is the maximum input voltage.

Compensation Components Selection



Select the appropriate compensation value by following procedure:

1. Calculate the R4 value with the following equation:

$$R4 < \frac{2\pi \times C_{OUT} \times 0.1 \times F_{OSC} \times V_{OUT}}{G_{EA} \times G_{CS} \times V_{REF}}$$

where G_{EA} is the error amplifier voltage gain, and G_{CS} is the current sense gain.

2. Calculate the C5 value with the following equation:

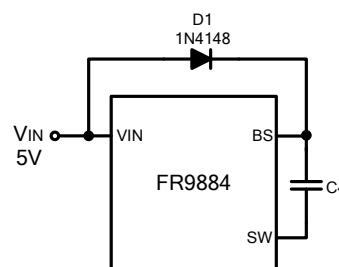
$$C5 > \frac{4}{2\pi \times R4 \times 0.1 \times F_{OSC}}$$

3. If the C_{OUT} ESR zero is less than half of the switching frequency, use C7 to cancel the ESR zero:

$$C7 = \frac{C_{OUT} \times R_{ESR}}{R4}$$

External Boost Diode Selection

For 5V input applications, it is recommended that an external boost diode could be added. This helps improving the efficiency. The boost diode can be a low cost one such as 1N4148.



This diode is also recommended for high duty cycle operation (when duty cycle > 65%, $V_{IN} < 15V$).

PCB Layout Recommendation

The device's performance and stability are dramatically affected by PCB layout. It is recommended to follow these general guidelines shown as below:

1. Place the input capacitors and output capacitors as close to the device as possible. The traces which connect to these capacitors should be as short and wide as possible to minimize parasitic inductance and resistance.
2. Place V_{IN} capacitors close to the V_{IN} pin.
3. Place feedback resistors close to the FB pin.
4. Place compensation components close to the COMP pin.
5. Keep the sensitive signal (FB, COMP) away from the switching signal (SW).
6. The exposed pad of the package should be soldered to an equivalent area of metal on the PCB. This area should connect to the GND plane and have multiple via connections to the back of the PCB as well as connections to intermediate PCB layers. The GND plane area which connects to the exposed pad should be maximized to improve thermal performance.
7. Multi-layer PCB design is recommended.

Application Information (Continued)

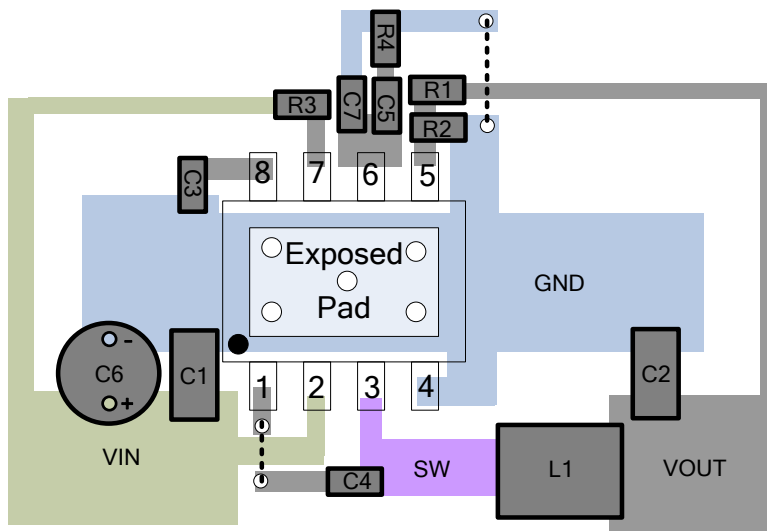
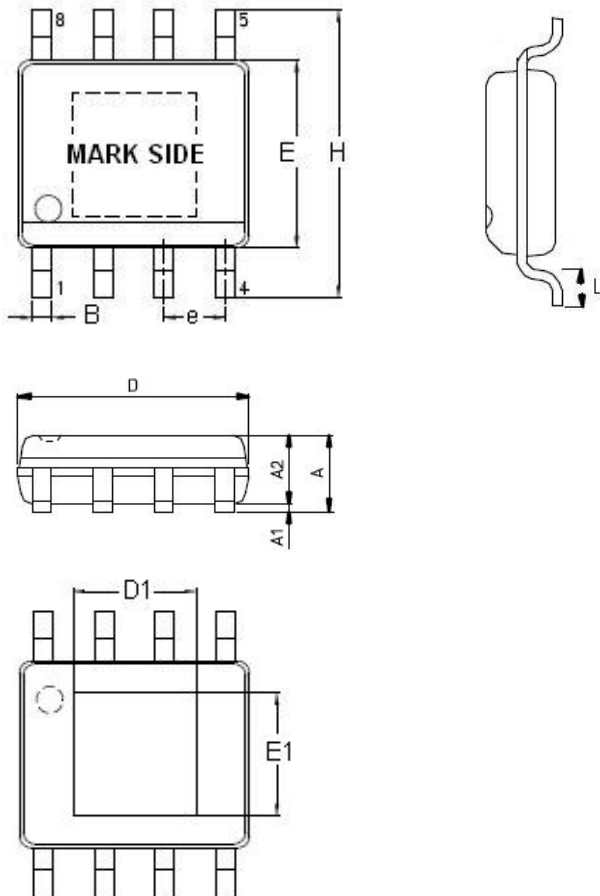


Figure 19. FR9884 Recommended Layout Diagram

Outline Information

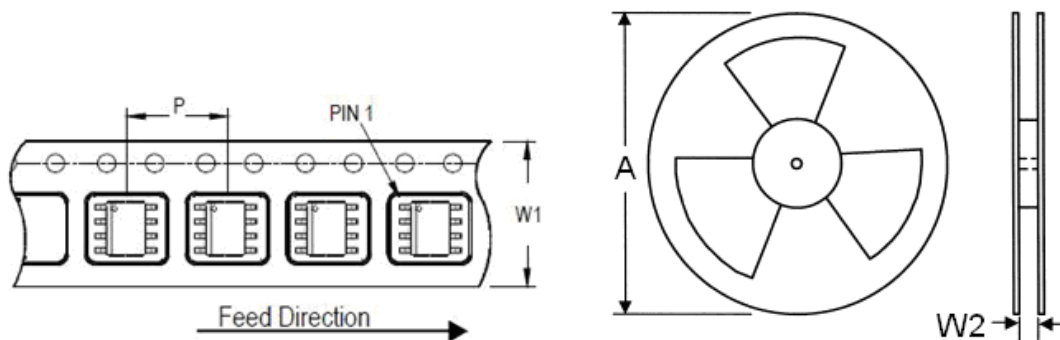
SOP-8 (Exposed Pad) Package (Unit: mm)



SYMBOLS UNIT	DIMENSION IN MILLIMETER	
	MIN	MAX
A	1.25	1.70
A1	0.00	0.15
A2	1.25	1.55
B	0.31	0.51
D	4.80	5.00
D1	3.04	3.50
E	3.80	4.00
E1	2.15	2.41
e	1.20	1.34
H	5.80	6.20
L	0.40	1.27

Note : Followed From JEDEC MO-012-E.

Carrier dimensions



Tape Size (W1) mm	Pocket Pitch (P) mm	Reel Size (A)		Reel Width (W2) mm	Empty Cavity Length mm	Units per Reel
		in	mm			
12	8	13	330	12.4	400~1000	2,500

Life Support Policy

Fitipower's products are not authorized for use as critical components in life support devices or other medical systems.